

50 V, 200 mA PNP general-purpose transistors Rev. 1 — 28 June 2010 F

Product data sheet

1. **Product profile**

1.1 General description

PNP general-purpose transistors in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

Table 1. **Product overview**

Type number	Package		NPN complement
	Nexperia	JEDEC	
2PB709BRL	SOT23	TO-236AB	2PD601BRL
2PB709BSL			2PD601BSL

1.2 Features and benefits

- Collector current $I_C \le -200 \text{ mA}$
- Two current gain selections
- AEC-Q101 qualified
- Small SMD plastic package

1.3 Applications

General-purpose switching and amplification

1.4 Quick reference data

Quick reference data Table 2.

• • •	B	A		-		
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	-50	V
I _C	collector current		-	-	-200	mA
h _{FE}	DC current gain	$V_{CE} = -10 \text{ V};$ $I_{C} = -2 \text{ mA}$	210	-	460	
	h _{FE} group R		210	-	340	
	h _{FE} group S		290	-	460	



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2. Pinning information

Table 3.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	base		
2	emitter		3
3	collector		1
			sym013

3. Ordering information

Table 4. Ordering information					
Type number	Package	,			
	Name	Description	Version		
2PB709BRL	-	plastic surface-mounted package; 3 leads	SOT23		
2PB709BSL					

4. Marking

Table 5. Marking codes	
Type number	Marking code ^[1]
2PB709BRL	MN*
2PB709BSL	MP*

- [1] * = -: made in Hong Kong
 - * = p: made in Hong Kong
 - * = t: made in Malaysia
 - * = W: made in China

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	-60	V
V_{CEO}	collector-emitter voltage	open base	-	-50	V
V_{EBO}	emitter-base voltage	open collector	-	-6	V
I _C	collector current		-	-200	mA
I _{CM}	peak collector current	single pulse; $t_p \leq 1 \text{ ms}$	-	-250	mA
I _{BM}	peak base current	single pulse; $t_p \leq 1 \text{ ms}$	-	-200	mA

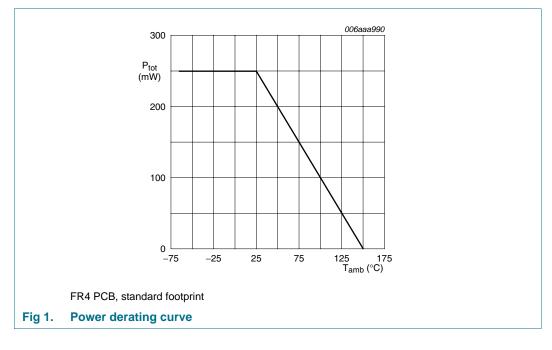
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Table 6. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

	0, (/		
Parameter	Conditions	Min	Max	Unit
total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	<u>[1]</u> -	250	mW
junction temperature		-	150	°C
ambient temperature		-55	+150	°C
storage temperature		-65	+150	°C
	total power dissipation junction temperature ambient temperature	total power dissipation $T_{amb} \le 25 \ ^{\circ}C$ junction temperatureambient temperature	total power dissipation $T_{amb} \le 25 \ ^{\circ}C$ [1]-junction temperature-ambient temperature-55	total power dissipation $T_{amb} \le 25 \text{ °C}$ [1]-250junction temperature-150ambient temperature-55+150

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



6. Thermal characteristics

Table 7.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	<u>[1]</u> _	-	500	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point		-	-	140	K/W

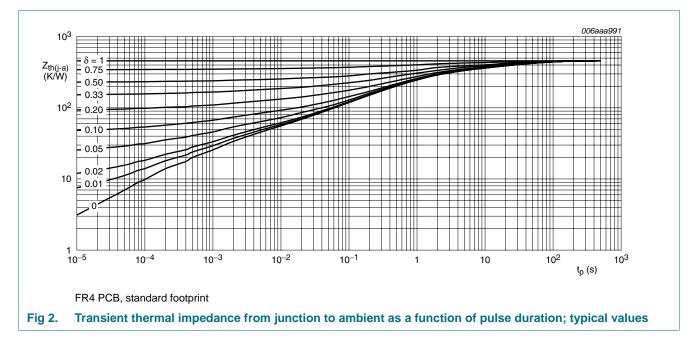
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

2PB709BRL_2PB709BSL

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7. Characteristics

Table 8.Characteristics

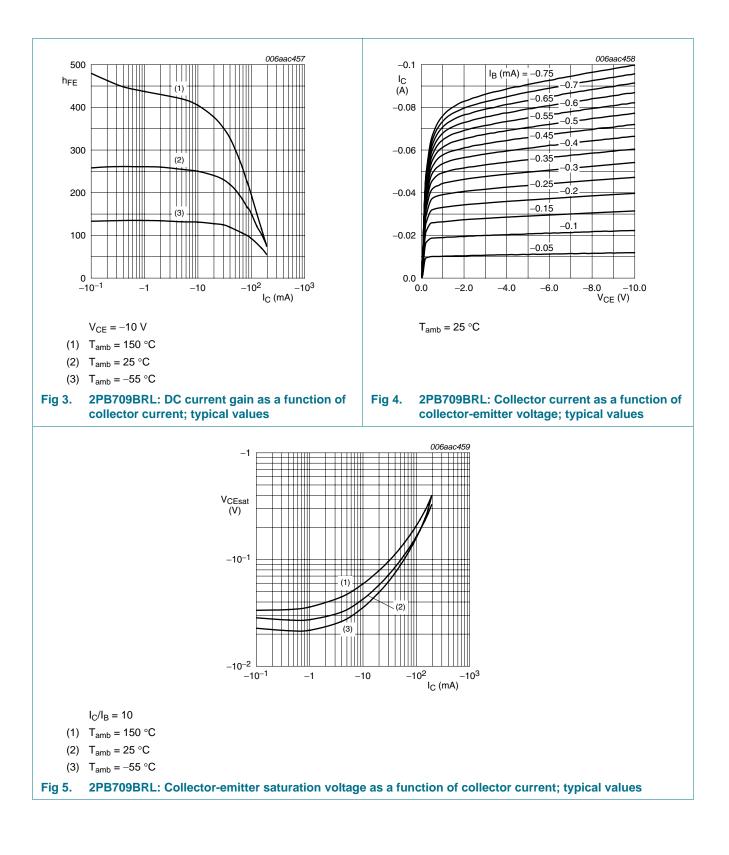
$T_{amb} = 25$	°C unless	otherwise	specified.	

Parameter	Conditions	М	in	Тур	Max	Unit		
collector-base cut-off current	$V_{CB} = -60 \text{ V}; I_E = 0 \text{ A}$	-		-	-10	nA		
	$\label{eq:V_CB} \begin{array}{l} V_{CB} = -60 \ V; \ I_{E} = 0 \ A; \\ T_{j} = 150 \ ^{\circ}C \end{array}$	-		-	-5	μA		
emitter-base cut-off current	$V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$	-		-	-10	nA		
DC current gain	V_{CE} = -10 V; I_C = -2 mA	21	10	-	460			
h _{FE} group R		21	0	-	340			
h _{FE} group S		29	90	-	460			
collector-emitter saturation voltage	I _C = -100 mA; I _B = -10 mA	<u>[1]</u> -		-	-250	mV		
transition frequency	$V_{CE} = -6 \text{ V}; I_{C} = -10 \text{ mA};$ f = 100 MHz	1(00	200	-	MHz		
collector capacitance	$V_{CB} = -10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-		-	3	pF		
	Parametercollector-base cut-off currentemitter-base cut-off currentDC current gainhFE group RhFE group Scollector-emitter saturation voltagetransition frequency	ParameterConditionscollector-base cut-off current $V_{CB} = -60 \text{ V}; I_E = 0 \text{ A}$ $V_{CB} = -60 \text{ V}; I_E = 0 \text{ A};$ $T_j = 150 \degree \text{C}$ emitter-base cut-off current $V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$ DC current gain $V_{CE} = -10 \text{ V}; I_C = -2 \text{ mA}$ hFE group R hFE group SIC = -100 \text{ mA}; I_B = -10 \text{ mA}transition frequency $V_{CE} = -6 \text{ V}; I_C = -10 \text{ mA};$ $I_B = -10 \text{ mA}$ transition frequency $V_{CE} = -6 \text{ V}; I_C = -10 \text{ mA};$ $f = 100 \text{ MHz}$ collector capacitance $V_{CB} = -10 \text{ V}; I_E = i_e = 0 \text{ A};$	ParameterConditionsMcollector-base cut-off current $V_{CB} = -60 \text{ V}; \text{ I}_E = 0 \text{ A}$ $V_{CB} = -60 \text{ V}; \text{ I}_E = 0 \text{ A};$ $T_j = 150 \text{ °C}$ -emitter-base cut-off current $V_{EB} = -50 \text{ V}; \text{ I}_C = 0 \text{ A}$ $V_{EB} = -5 \text{ V}; \text{ I}_C = 0 \text{ A}$ -DC current gain $V_{CE} = -10 \text{ V}; \text{ I}_C = -2 \text{ mA}$ 24hFE group R hFE group S25collector-emitter saturation voltageI_C = -100 \text{ mA}; I_B = -10 \text{ mA}[1] 1transition frequency $V_{CE} = -6 \text{ V}; \text{ I}_C = -10 \text{ mA};f = 100 \text{ MHz}$ 10collector capacitance $V_{CB} = -10 \text{ V}; \text{ I}_E = i_e = 0 \text{ A};$ -	$\begin{array}{c c} \mbox{Parameter} & \mbox{Conditions} & \mbox{Min} \\ \hline \mbox{collector-base cut-off} & \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ $	$\begin{tabular}{ c c c } \hline Parameter & Conditions & Min & Typ \\ \hline collector-base cut-off current & $V_{CB} = -60 \ V; \ I_E = 0 \ A$ & $-$ & $-$ & $-$ & $V_{CB} = -60 \ V; \ I_E = 0 \ A$; & $-$ & $-$ & $-$ & $V_{CB} = -60 \ V; \ I_E = 0 \ A$; & $-$ & $-$ & $-$ & $-$ & $-$ & $V_{CB} = -60 \ V; \ I_E = 0 \ A$; & $-$ $	$\begin{array}{ c c c c } \hline Parameter & Conditions & Min & Typ & Max \\ \hline collector-base cut-off current & $V_{CB} = -60 \ V; \ I_E = 0 \ A$ & - & - & -10$ \\ \hline $V_{CB} = -60 \ V; \ I_E = 0 \ A$; & - & - & -10$ \\ \hline $V_{CB} = -60 \ V; \ I_E = 0 \ A$; & - & - & -5$ \\ \hline $V_{CB} = -60 \ V; \ I_E = 0 \ A$; & - & - & -5$ \\ \hline $V_{CB} = -60 \ V; \ I_E = 0 \ A$; & - & - & -5$ \\ \hline $V_{CB} = -50 \ V; \ I_C = 0 \ A$ & - & - & -5$ \\ \hline $emitter-base \ cut-off current & $V_{EB} = -5 \ V; \ I_C = 0 \ A$ & - & - & -10$ \\ \hline $PC \ current \ gain & $V_{CE} = -10 \ V; \ I_C = -2 \ mA$ & 210 & - & 460$ \\ \hline $h_{FE} \ group \ R$ & 210 & - & 340$ \\ \hline $h_{FE} \ group \ S$ & 290 & - & 460$ \\ \hline $collector-emitter$ & $I_C = -100 \ mA$; & 11 - & - & -250$ \\ \hline $saturation \ voltage $ & $I_{C} = -6 \ V; \ I_C = -10 \ mA$; & 100 & 200 & - \\ \hline $transition \ frequency $ & $V_{CE} = -6 \ V; \ I_C = -10 \ mA$; & 100 & 200 & - \\ \hline $collector \ capacitance $ & $V_{CB} = -10 \ V; \ I_E = i_e = 0 \ A$; & - & & 3 \\ \hline \end{tabular}$		

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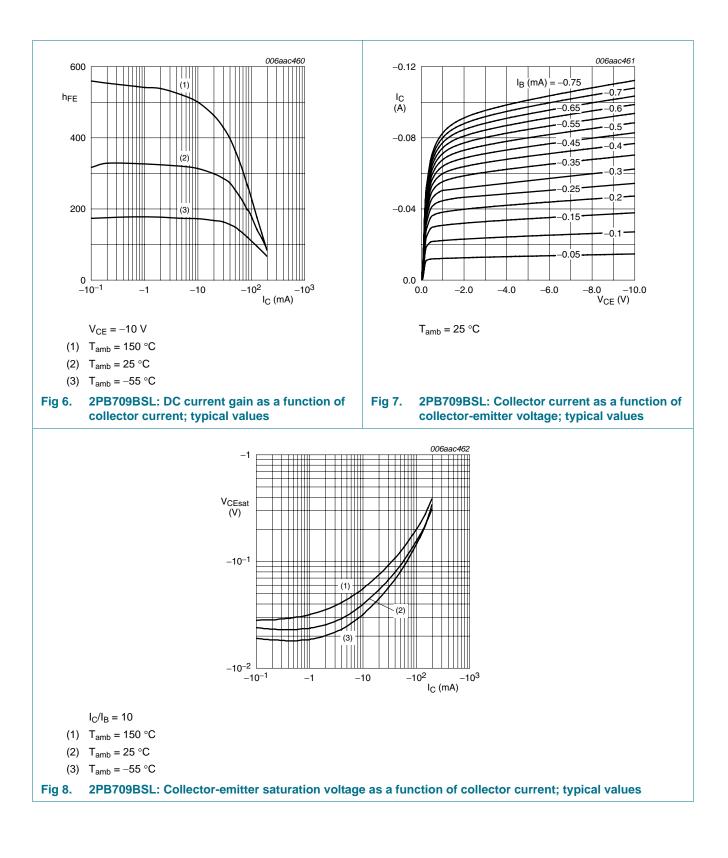
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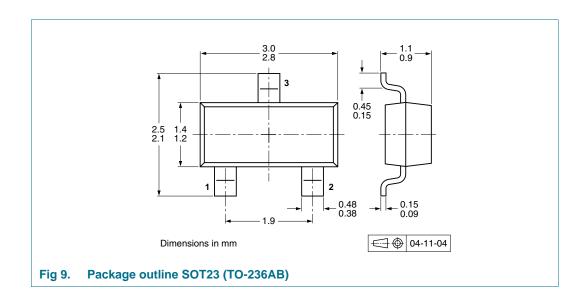
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8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



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10. Packing information

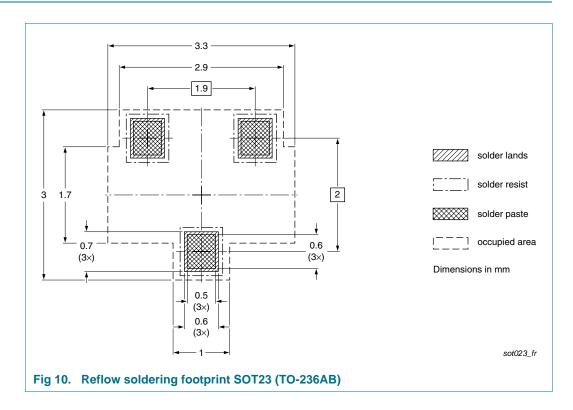
Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

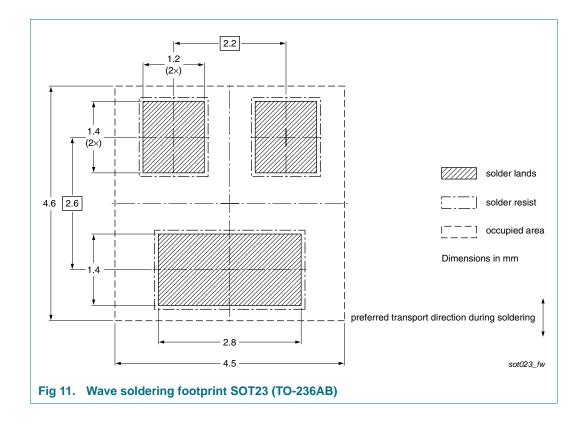
Type number	Package	Description Packing quantit		quantity
			3000	10000
2PB709BRL	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235
2PB709BSL				

[1] For further information and the availability of packing methods, see <u>Section 14</u>.

11. Soldering



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12. Revision history

Table 10. Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
2PB709BRL_2PB709BSL v.1	20100628	Product data sheet	-	-

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13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

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